VS-U5FH30BA60



FRED Pt[®] Gen 5 Ultrafast Single Phase Bridge (Power Modules), 600 V, 30 A



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PRIMARY CHARACTERISTICS							
V _{RRM}	600 V						
I _O at T _C = 131 °C	30 A						
V _F (typical) at 30 A, per diode	1.6 V						
t _{rr} (typical) at 30 A, per diode	63 ns						
Туре	Modules - Bridge, Hyperfast						
Package	SOT-227						
Circuit configuration	Single phase bridge						

FEATURES

- Ultrafast and optimized Q_{rr}
- · Best in class forward voltage drop and switching losses trade off



COMPLIANT

- Optimized for high speed operation
- 175 °C maximum operating junction temperature
- · Electrically isolated base plate
- Large creepage distance between terminal
- Simplified mechanical designs, rapid assembly
- Designed and qualified for industrial level
- UL approved file E78996
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, the VS-U5FH30BA60 is the right choice for high frequency converters, both soft switched / resonant. The semiconductor in the SOT-227 package is isolated from the copper base plate, allowing for common heatsinks and compact assemblies to be built.

These modules are specifically designed to improve efficiency of PFC and output rectification stages of EV / HEV battery charging stations, booster stage of solar inverters, and UPS applications, these devices are perfectly matched to operate with MOSFETs or high speed IGBTs.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
1		30	А				
I _O	T _C	131	°C				
1	50 Hz	290	•				
IFSM	60 Hz	305	A				
l ² t	50 Hz	424	– A ² s				
1-1	60 Hz	387	A-S				
V _{RRM}		650	V				
TJ		-55 to +175	°C				

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS									
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V						
VS-U5FH30BA60	60	600	600						

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ELECTRICAL SPECIFICATIONS ($T_J = 25$ °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Cathode to anode breakdown voltage	V _{BR}	I _R = 100 μA	600	-	-			
Forward voltage	M	I _F = 30 A	-	1.6	2.1	V		
Forward voltage	V _{FM}	I _F = 30 A, T _J = 150 °C	-	1.26	-			
		V _R = 600 V	-	0.1	30			
Reverse leakage current	I _{RM}	T _J = 125 °C, V _R = 600 V	-	14	-	μA		
		T _J = 150 °C, V _R = 600 V	-	53	-			
RMS isolation voltage base plate	VISOL	f = 50 Hz, any terminal to case, t = 1 min	2500	-	-	V		

FORWARD CONDUCTION							
PARAMETER	SYMBOL	. TEST CONDITIONS VALUES UNIT					
Maximum DC output current	1	Resistive or ind	luctive load		30	А	
at case temperature	Ι _Ο				131	°C	
		t = 10 ms	No voltage		291		
Maximum peak, one-cycle	1	t = 8.3 ms	reapplied	- Initial T _J = 25 °C	305	А	
non-repetitive forward current	I _{FSM}	t = 10 ms	100 % V _{RRM}		245		
		t = 8.3 ms	reapplied		256	1	
		t = 10 ms	No voltage		424	A ² s	
Maximum I ² t for fusing	l ² t	t = 8.3 ms	reapplied		387		
Maximum r-t for fusing		t = 10 ms	100 % V _{RRM}		300		
		t = 8.3 ms	reapplied		274		
Maximum I ² \sqrt{t} for fusing	l²√t	$I^{2}t$ for time $t_{x} =$	$I_2 \sqrt{t} \; x \; \sqrt{t_x}; 0.1 \leq t_x \leq 1$	0 ms, $V_{RRM} = 0 V$	4244	kA²√s	
Low level of threshold voltage, per leg	V _{F(T0)1}	0.96				V	
Low level value of forward slope resistance	r _{f1}	$(16.7 \% \text{ x } \pi \text{ x } I_{F(AV)}) < I < \pi \text{ x } I_{F(AV)}, T_J = T_J \text{ maximum}$ $25.02 \text{ m}\Omega$				mΩ	
High level of threshold voltage, per leg	V _{F(T0)2}				1.31	V	
High level value of forward slope resistance	r _{f2}	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$ $23.71 \text{ m}\Omega$				mΩ	
Maximum forward voltage, per diode	V _{FM}	I _F = 30 A			2.1	V	

DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST	CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Poverse recovery time	+	T _J = 25 °C		-	57	-	20	
Reverse recovery time	t _{rr}	T _J = 125 °C	$I_{\rm F} = 30 \text{A},$	-	62	-	ns	
Deals receiver a current		T _J = 25 °C		-	12	-	٨	
Peak recovery current	I _{RRM}	T _J = 125 °C	di _F /dt = 1000 A/µs, V _B = 400 V	-	25	-	A	
Reverse recovery charge	0	0	$T_J = 25 \ ^\circ C$		-	0.3	-	
Reverse recovery charge Q _{rr}		T _J = 125 °C		-	0.9	-	μC	
Junction capacitance	CT	V _R = 600 V, f :	= 1 MHz	-	29	-	pF	

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Thermal resistance junction to case, per diode	R _{thJC}		-	-	1.39	°C/W		
Thermal resistance case to heatsink, per module	R _{thCS}	Flat, greased, surface	-	0.05	-	C/W		
Weight			-	30	-	g		
Mounting torque		Torque per diode	-	-	1.1 (9.7)	Nm (lbf.in)		
Mounting torque		Torque to heatsink	-	-	1.8 (15.9)	Nm (lbf.in)		
Case style				S	DT-227			

Revision: 22-Apr-2024

Document Number: 96937

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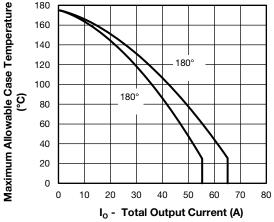


Fig. 1 - Current Rating Characteristics

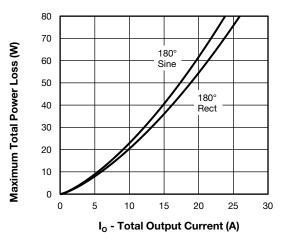


Fig. 2 - Total Power Loss Characteristics

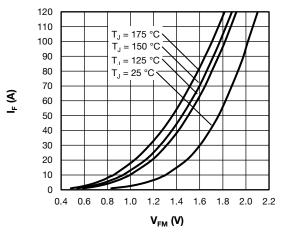


Fig. 3 - Typical Forward Voltage Drop Characteristics

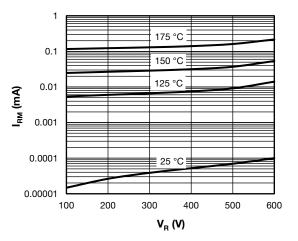
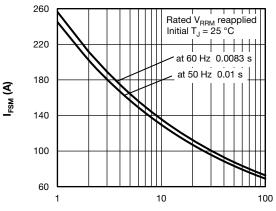


Fig. 4 - Typical Values of Reverse Current



Number of Equal Amplitude Half Cycle Current Pulses (N)

Fig. 5 - Non-Repetitive Peak Forward Surge Current vs. Number Pulses

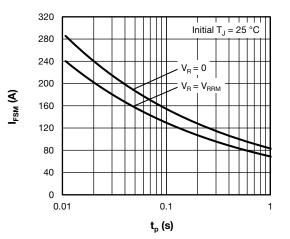


Fig. 6 - Non-Repetitive peak Forward Surge Current vs. Pulse Duration

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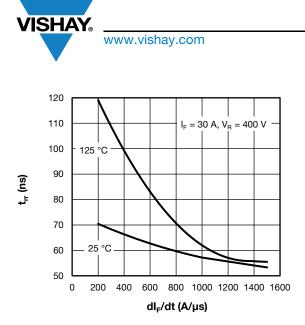


Fig. 7 - Diode Reverse Recovery Time vs. dl_Fdt

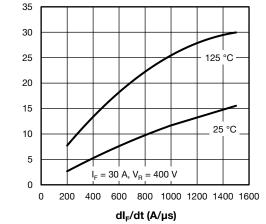


Fig. 8 - Diode Reverse Recovery Current vs. dl_Fdt

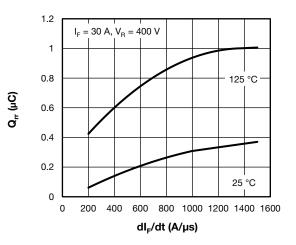


Fig. 9 - Diode Reverse Recovery Charge vs. dl_Fdt

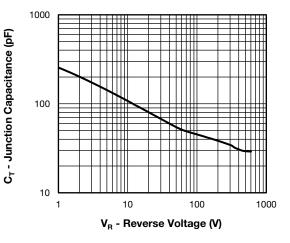


Fig. 10 - Junction Capacitance

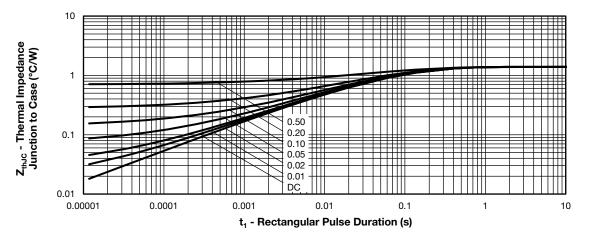


Fig. 11 - Maximum Thermal Impedance Junction to Case

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I_{rr} (A)



ORDERING INFORMATION TABLE

Device code	vs-	U5F	н	30	В	Α	60
		2	3	4	5	6	7
	1 .	- Visł	nay Sem	niconduo	ctors pr	oduct	
	2 - U5F = Gen 5 FRED $Pt^{(B)}$ family						
	3 -	- H = Ultrafast FRED Pt [®] diode					
	4	- Cur	rent rati	ng per r	nodule	(30 = 30) A)
	5 -	• B =	circuit o	configur	ation (S	ingle pł	nase bri
	6	- Pac	kage in	dicator	(SOT-22	27 stand	dard ins
	7	- Volt	tage rati	ng (60 =	= 600 V)		

CIRCUIT CONFIGURATION							
CIRCUIT	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING					
Single phase bridge	В	4 (AC) 3 (-) \downarrow (AC) 3 (-) \downarrow (AC) 3 (-) \downarrow (AC) 4 \downarrow (AC) 3 (-) \downarrow (AC) 4 \downarrow (AC) 3 (-) \downarrow (AC) 4 \downarrow (AC) 3 \downarrow (AC) 3					

LINKS TO RELATED DOCUMENTS						
Dimensions www.vishay.com/doc?95423						
Packaging information	www.vishay.com/doc?95425					



SOT-227 Generation 2

DIMENSIONS in millimeters (inches)



Note

• Controlling dimension: millimeter



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Revision: 01-Jan-2025

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